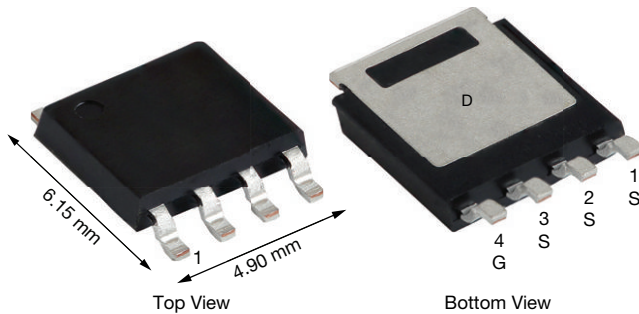
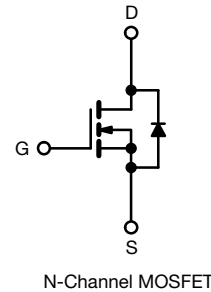


Automotive N-Channel 80 V (D-S) 175 °C MOSFET

PowerPAK® SO-8L

FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

 AUTOMOTIVE
GRADE

RoHS
COMPLIANT
HALOGEN
FREE


N-Channel MOSFET

PRODUCT SUMMARY

| | |
|---|----------------|
| V _{DS} (V) | 80 |
| R _{DS(on)} (Ω) at V _{GS} = 10 V | 0.0075 |
| I _D (A) | 118 |
| Configuration | Single |
| Package | PowerPAK SO-8L |

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

| PARAMETER | SYMBOL | LIMIT | UNIT |
|---|-----------------------------------|-------------------------|-----------------|
| Drain-source voltage | V _{DS} | 80 | V |
| Gate-source voltage | V _{GS} | ± 20 | |
| Continuous drain current | I _D | T _C = 25 °C | 118 |
| | | T _C = 125 °C | 68 |
| Continuous source current (diode conduction) | I _S | 210 | A |
| Pulsed drain current | I _{DM} | 240 | |
| Single pulse avalanche current | L = 0.1 mH | I _{AS} | 32 |
| Single pulse avalanche energy | | | E _{AS} |
| Maximum power dissipation | P _D | T _C = 25 °C | 234 |
| | | T _C = 125 °C | 78 |
| Operating junction and storage temperature range | T _J , T _{stg} | -55 to +175 | °C |
| Soldering recommendations (peak temperature) ^b | | 260 | |

THERMAL RESISTANCE RATINGS

| PARAMETER | SYMBOL | LIMIT | UNIT |
|--------------------------|-------------------|-------|------|
| Junction-to-ambient | R _{thJA} | 42 | °C/W |
| Junction-to-case (drain) | R _{thJC} | 0.64 | |

Notes

- When mounted on 1" square PCB (FR4 material)
- See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



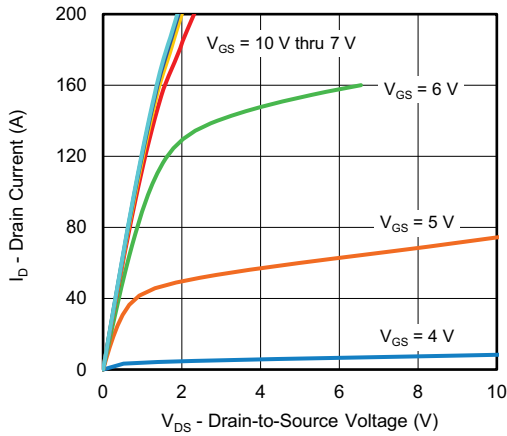
| SPECIFICATIONS ($T_C = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | | |
|--|---------------|--|------|--------|-----------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| Static | | | | | | |
| Drain-source breakdown voltage | V_{DS} | $V_{GS} = 0, I_D = 250\text{ }\mu\text{A}$ | 80 | - | - | V |
| Gate-source threshold voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$ | 2.2 | 2.7 | 3.5 | |
| Gate-source leakage | I_{GSS} | $V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$ | - | - | ± 100 | nA |
| Zero gate voltage drain current | I_{DSS} | $V_{GS} = 0\text{ V}$ $V_{DS} = 80\text{ V}$ | - | - | 1 | μA |
| | | $V_{GS} = 0\text{ V}$ $V_{DS} = 80\text{ V}, T_J = 125\text{ }^\circ\text{C}$ | - | - | 50 | |
| | | $V_{GS} = 0\text{ V}$ $V_{DS} = 80\text{ V}, T_J = 175\text{ }^\circ\text{C}$ | - | - | 250 | |
| On-state drain current ^a | $I_{D(on)}$ | $V_{GS} = 10\text{ V}$ $V_{DS} \geq 5\text{ V}$ | 30 | - | - | A |
| Drain-source on-state resistance ^a | $R_{DS(on)}$ | $V_{GS} = 10\text{ V}$ $I_D = 15\text{ A}$ | - | 0.0060 | 0.0075 | Ω |
| | | $V_{GS} = 10\text{ V}$ $I_D = 15\text{ A}, T_J = 125\text{ }^\circ\text{C}$ | - | - | 0.0124 | |
| | | $V_{GS} = 10\text{ V}$ $I_D = 15\text{ A}, T_J = 175\text{ }^\circ\text{C}$ | - | - | 0.0156 | |
| Forward transconductance ^b | g_{fs} | $V_{DS} = 15\text{ V}, I_D = 10\text{ A}$ | - | 67 | - | S |
| Dynamic ^b | | | | | | |
| Input capacitance | C_{iss} | $V_{GS} = 0\text{ V}$ $V_{DS} = 25\text{ V}, f = 1\text{ MHz}$ | - | 2484 | 3478 | μF |
| Output capacitance | C_{oss} | | - | 1029 | 1441 | |
| Reverse transfer capacitance | C_{rss} | | - | 76 | 107 | |
| Total gate charge ^c | Q_g | $V_{GS} = 10\text{ V}$ $V_{DS} = 40\text{ V}, I_D = 30\text{ A}$ | - | 46 | 69 | nC |
| Gate-source charge ^c | Q_{gs} | | - | 12 | - | |
| Gate-drain charge ^c | Q_{gd} | | - | 13 | - | |
| Gate resistance | R_g | $f = 1\text{ MHz}$ | 0.6 | 1.2 | 1.8 | Ω |
| Turn-on delay time ^c | $t_{d(on)}$ | $V_{DD} = 40\text{ V}, R_L = 1.33\text{ }\Omega,$ $I_D \cong 30\text{ A}, V_{GEN} = 10\text{ V}, R_g = 1\text{ }\Omega$ | - | 12 | 18 | ns |
| Rise time ^c | t_r | | - | 4 | 6 | |
| Turn-off delay time ^c | $t_{d(off)}$ | | - | 23 | 35 | |
| Fall time ^c | t_f | | - | 5 | 8 | |
| Source-Drain Diode Ratings and Characteristics ^b | | | | | | |
| Pulsed current ^a | I_{SM} | | - | - | 240 | A |
| Forward voltage | V_{SD} | $I_F = 15\text{ A}, V_{GS} = 0\text{ V}$ | - | - | 1.1 | V |
| Body diode reverse recovery time | t_{rr} | $I_F = 10\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$ | - | 37 | 74 | ns |
| Body diode reverse recovery charge | Q_{rr} | | - | 38 | 76 | nC |
| Reverse recovery fall time | t_a | | - | 21 | - | ns |
| Reverse recovery rise time | t_b | | - | 15 | - | |
| Body diode peak reverse recovery current | $I_{RM(REC)}$ | | | - | -2.0 | - |

Notes

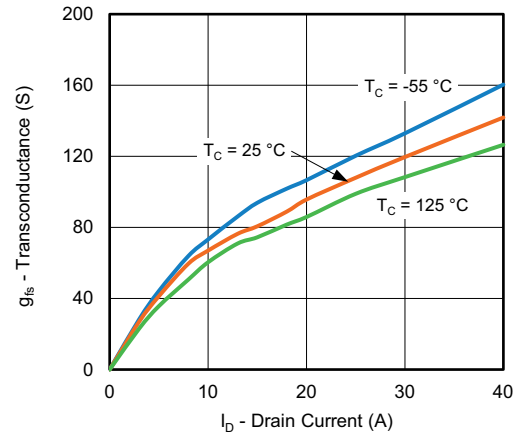
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

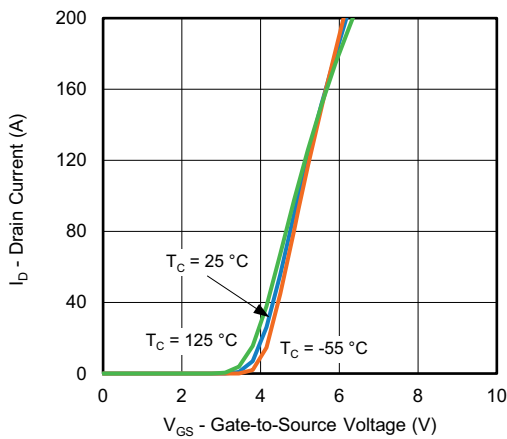
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



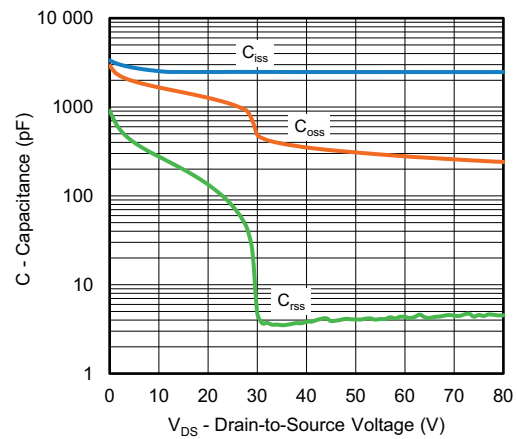
Output Characteristics



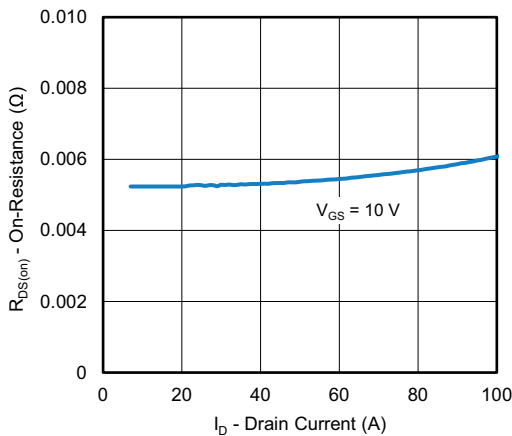
Transconductance



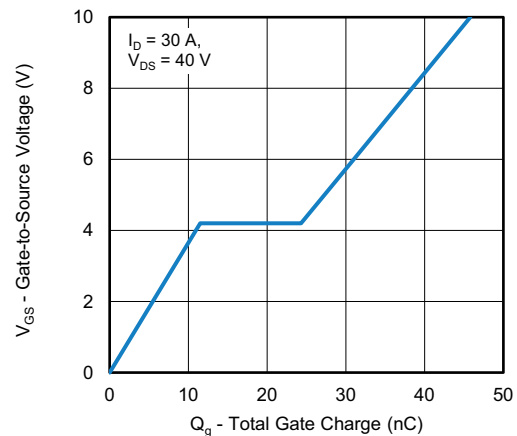
Transfer Characteristics



Capacitance



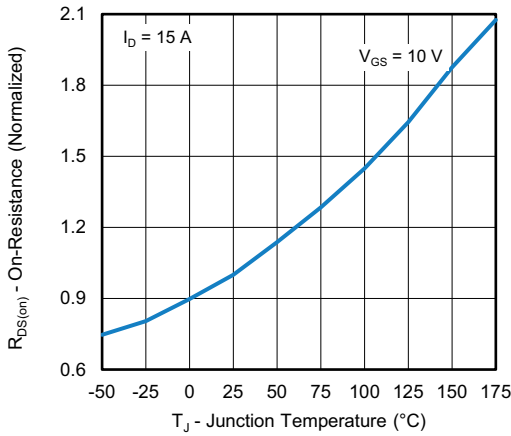
On-Resistance vs. Drain Current



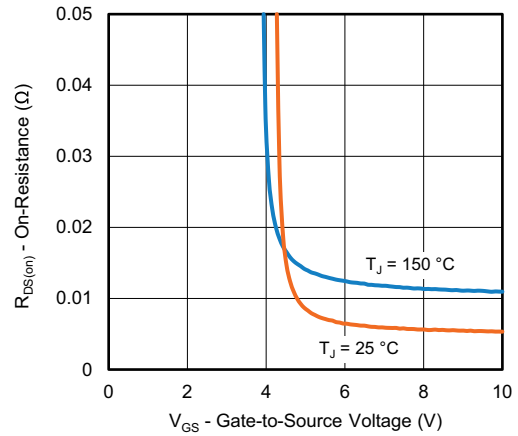
Gate Charge



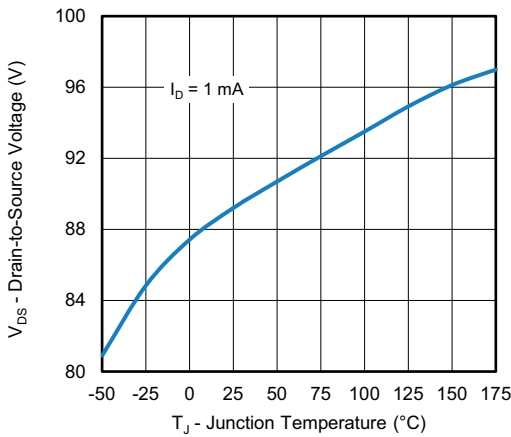
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



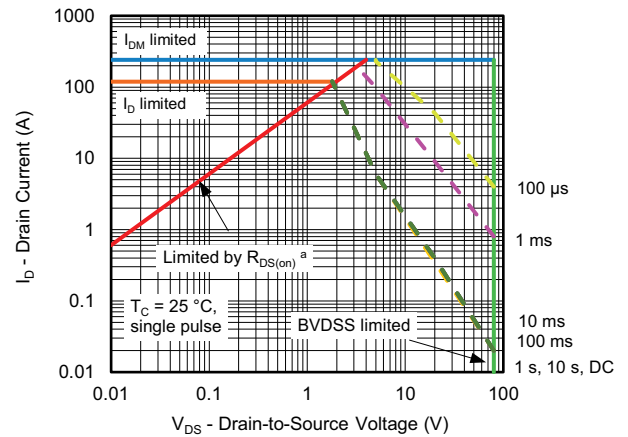
On-Resistance vs. Junction Temperature



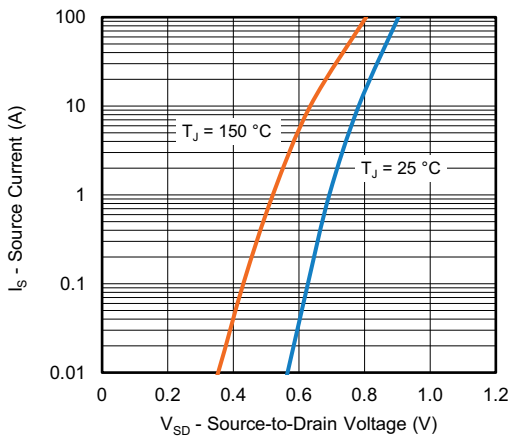
On-Resistance vs. Gate-to Source Voltage



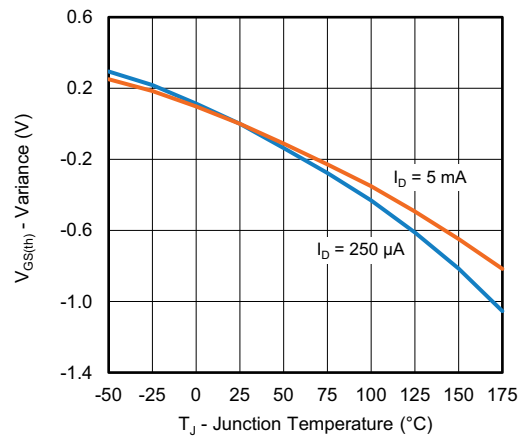
Drain Source Breakdown vs. Junction Temperature



Safe Operating Area



Source Drain Diode Forward Voltage



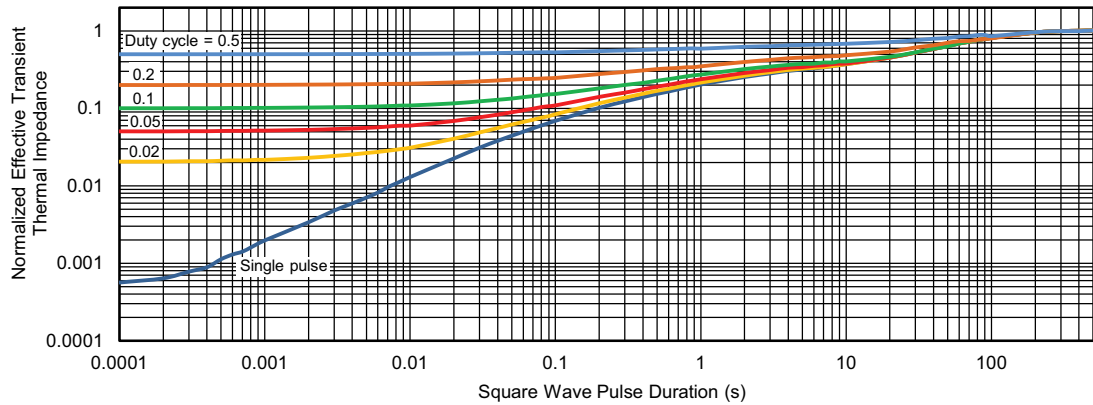
Threshold Voltage

Note

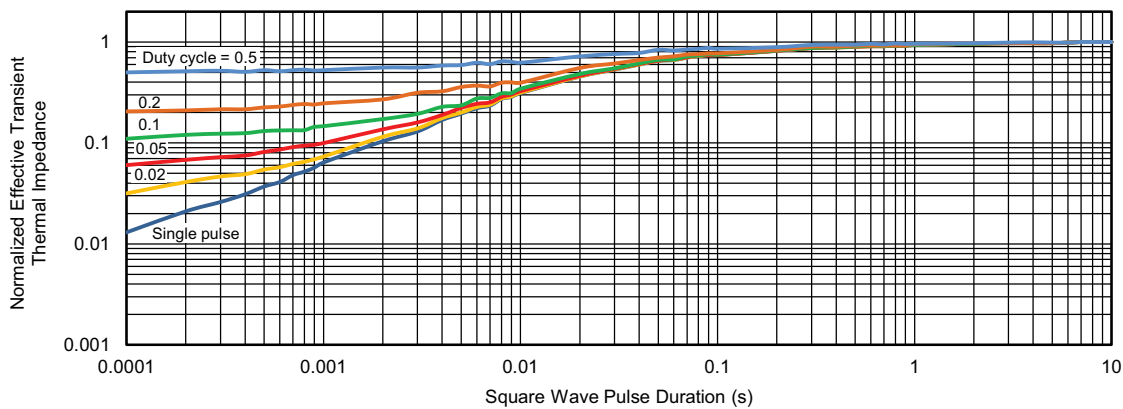
a. V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

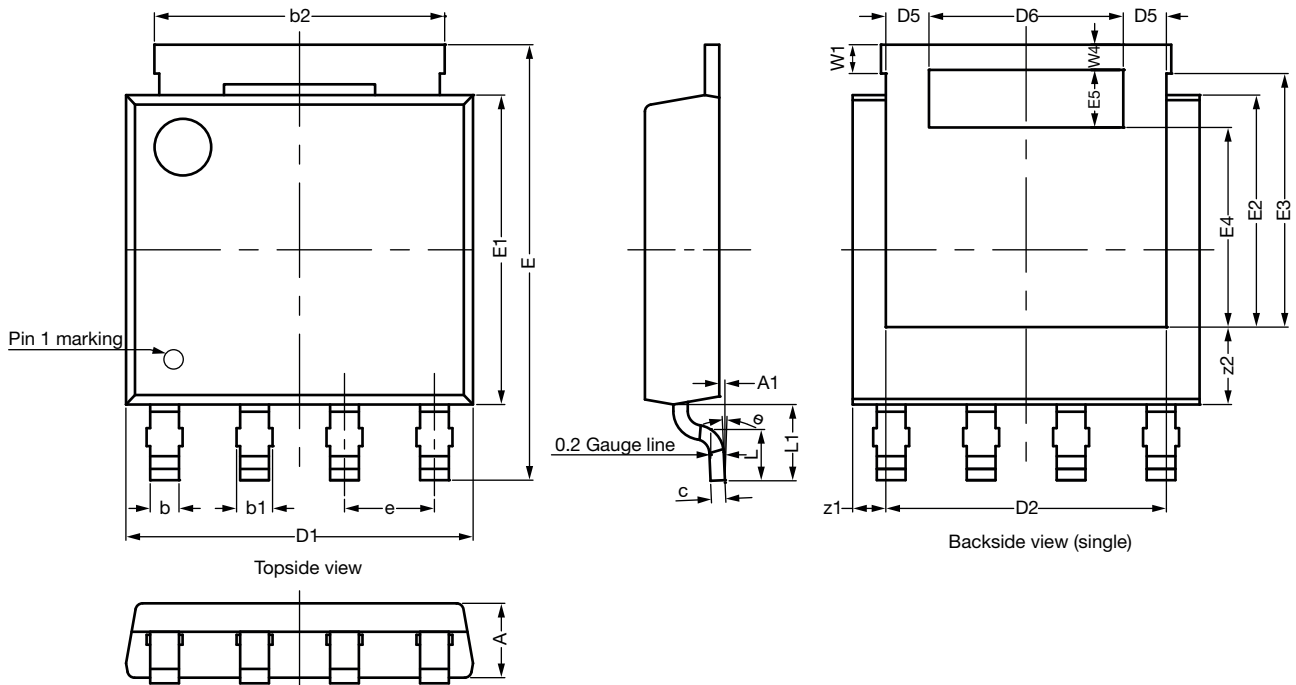
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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PowerPAK® SO-8L (PPKS08LWLA) Case Outline 3



| DIM. | MILLIMETERS | | | INCHES | | |
|------|-------------|------|-------|-----------|-------|-------|
| | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A | 1.00 | 1.05 | 1.10 | 0.039 | 0.041 | 0.043 |
| A1 | 0.00 | --- | 0.127 | 0.000 | --- | 0.005 |
| b | 0.33 | 0.41 | 0.49 | 0.013 | 0.016 | 0.019 |
| b1 | 0.43 | 0.51 | 0.59 | 0.017 | 0.020 | 0.023 |
| b2 | 4.00 | 4.10 | 4.20 | 0.157 | 0.161 | 0.165 |
| c | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 |
| D1 | 4.80 | 4.90 | 5.00 | 0.189 | 0.193 | 0.197 |
| D2 | 3.86 | 3.96 | 4.06 | 0.152 | 0.156 | 0.160 |
| D5 | 0.51 | 0.61 | 0.71 | 0.020 | 0.024 | 0.028 |
| D6 | 2.64 | 2.74 | 2.84 | 0.104 | 0.108 | 0.112 |
| e | 1.27 BSC | | | 0.050 BSC | | |
| E | 6.05 | 6.15 | 6.25 | 0.238 | 0.242 | 0.246 |
| E1 | 4.27 | 4.37 | 4.47 | 0.168 | 0.172 | 0.176 |
| E2 | 3.18 | 3.28 | 3.38 | 0.125 | 0.129 | 0.133 |
| E3 | 3.48 | 3.58 | 3.68 | 0.137 | 0.141 | 0.145 |
| E4 | 2.72 | 2.82 | 2.92 | 0.107 | 0.111 | 0.115 |
| E5 | 0.71 | 0.81 | 0.91 | 0.028 | 0.032 | 0.036 |
| L | 0.62 | 0.72 | 0.82 | 0.024 | 0.028 | 0.032 |
| L1 | 0.92 | 1.07 | 1.22 | 0.036 | 0.042 | 0.048 |
| W1 | 0.31 | 0.41 | 0.51 | 0.012 | 0.016 | 0.020 |
| W4 | 0.31 | 0.36 | 0.41 | 0.012 | 0.014 | 0.016 |
| z1 | 0.37 | 0.47 | 0.57 | 0.015 | 0.019 | 0.022 |
| z2 | 0.99 | 1.09 | 1.19 | 0.039 | 0.043 | 0.047 |
| θ | 0° | --- | 5° | 0° | --- | 5° |

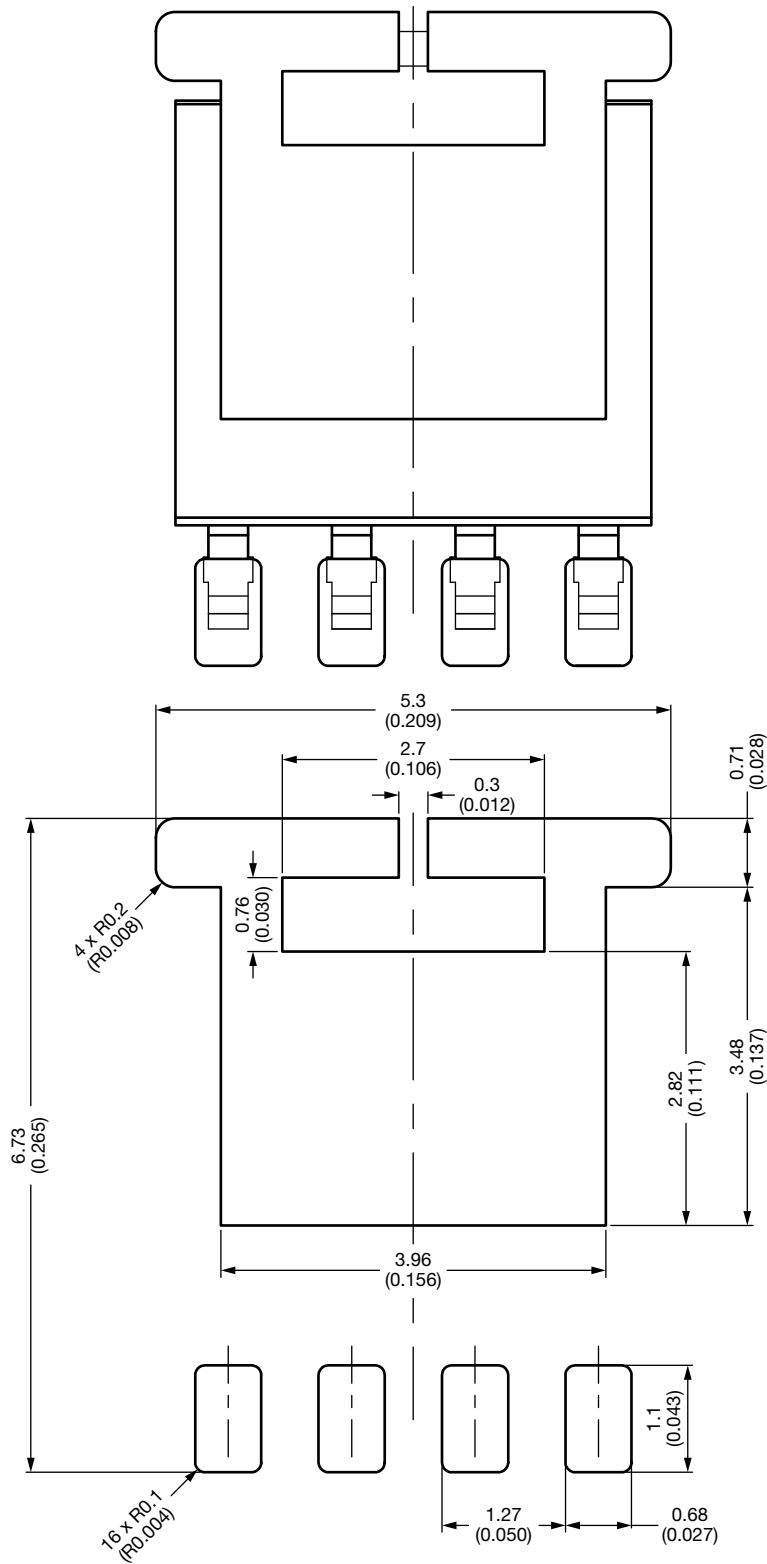
ECN: C23-1016-Rev. D, 18-Sep-2023
 DWG: 6067

Note

- Millimeter will govern



Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)



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